

MC74HCT14A

Hex Schmitt-Trigger Inverter with LSTTL Compatible Inputs

High-Performance Silicon-Gate CMOS

The MC74HCT14A may be used as a level converter for interfacing TTL or NMOS outputs to high-speed CMOS inputs.

The HCT14A is identical in pinout to the LS14.

The HCT14A is useful to “square up” slow input rise and fall times. Due to the hysteresis voltage of the Schmitt trigger, the HCT14A finds applications in noisy environments.

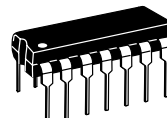
- Output Drive Capability: 10 LSTTL Loads
- TTL/NMOS-Compatible Input Levels
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 4.5 to 5.5 V
- Low Input Current: 1.0 μ A
- In Compliance with the Requirements Defined by JEDEC Standard No. 7A
- Chip Complexity: 72 FETs or 18 Equivalent Gates



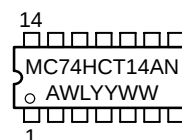
ON Semiconductor

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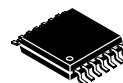
MARKING DIAGRAMS



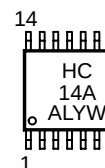
PDIP-14
N SUFFIX
CASE 646



SOIC-14
D SUFFIX
CASE 751A



TSSOP-14
DT SUFFIX
CASE 948G

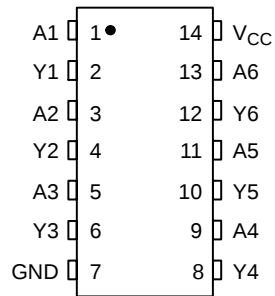


A = Assembly Location
L, WL = Wafer Lot
Y, YY = Year
W, WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping
MC74HCT14AN	PDIP-14	2000/Box
MC74HCT14AD	SOIC-14	55/Rail
MC74HCT14ADR2	SOIC-14	2500/Reel
MC74HC14ADT	TSSOP-14	96/Rail
MC74HC14ADTR2	TSSOP-14	2500/Reel

MC74HCT14A



FUNCTION TABLE

Input A	Output Y
L	H
H	L

Figure 1. Pin Assignment

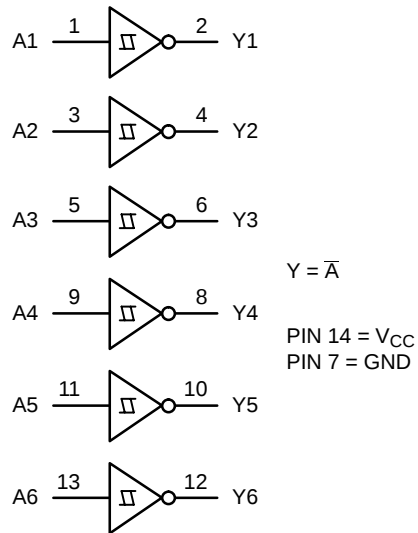


Figure 2. Logic Diagram

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MAXIMUM RATINGS (Note 1)

Symbol	Parameter	Value	Unit
V_{CC}	DC Supply Voltage (Referenced to GND)	− 0.5 to + 7.0	V
V_I	DC Input Voltage (Referenced to GND)	− 0.5 to $V_{CC} + 0.5$	V
V_O	DC Output Voltage (Referenced to GND)	− 0.5 to $V_{CC} + 0.5$	V
I_{IK}	DC Input Diode Current	± 20	mA
I_{OK}	DC Output Diode Current	± 25	mA
I_O	DC Output Sink Current	± 25	mA
I_{CC}	DC Supply Current per Supply Pin	± 50	mA
I_{GND}	DC Ground Current per Ground Pin	± 50	mA
T_{STG}	Storage Temperature Range	− 65 to + 150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
T_J	Junction Temperature under Bias	+ 150	°C
θ_{JA}	Thermal Resistance PDIP SOIC TSSOP	78 125 170	°C/W
P_D	Power Dissipation in Still Air at 85°C PDIP SOIC TSSOP	750 500 450	mW
MSL	Moisture Sensitivity	Level 1	
F_R	Flammability Rating Oxygen Index: 30% – 35%	UL–94–VO (0.125 in)	
V_{ESD}	ESD Withstand Voltage Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	>4000 >300 >1000	V
$I_{Latch-Up}$	Latch-Up Performance Above V_{CC} and Below GND at 85°C (Note 5)	± 300	mA

1. Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Extended exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum-rated conditions is not implied.
2. Tested to EIA/JESD22–A114–A.
3. Tested to EIA/JESD22–A115–A.
4. Tested to JESD22–C101–A.
5. Tested to EIA/JESD78.
6. For high frequency or heavy load considerations, see the ON Semiconductor High-Speed CMOS Data Book (DL129/D).

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V_{CC}	DC Supply Voltage (Referenced to GND)	4.5	5.5	V
V_I, V_O	DC Input Voltage, Output Voltage (Referenced to GND)	0	V_{CC}	V
T_A	Operating Temperature, All Package Types	− 55	+ 125	°C
t_r, t_f	Input Rise and Fall Time (Figure 3)	—	(Note 7)	ns

7. No Limit when $V_I \approx 50\% V_{CC}$, $I_{CC} > 1$ mA.
8. Unused inputs may not be left open. All inputs must be tied to a high-logic voltage level or a low-logic input voltage level.

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DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

Symbol	Parameter	Test Conditions	V _{CC} Volts	Temperature Limit						Unit
				– 55°C to 25°C		≤ 85°C		≤ 125°C		
				Min	Max	Min	Max	Min	Max	
V _{T+} max	Maximum Positive–Going Input Threshold Voltage	V _O = 0.1 V or V _{CC} – 0.1 V I _{out} ≤ 20 μA	4.5 5.5	 1.9 2.1	 1.9 2.1	 1.9 2.1	 1.9 2.1	 1.9 2.1	V	
V _{T+} min	Minimum Positive–Going Input Threshold Voltage	V _O = 0.1 V or V _{CC} – 0.1 V I _{out} ≤ 20 μA	4.5 5.5	1.2 1.4	 1.2 1.4	 1.2 1.4	 1.2 1.4	 1.2 1.4	V	
V _{T–} max	Maximum Positive–Going Input Threshold Voltage	V _O = 0.1 V or V _{CC} – 0.1 V I _{out} ≤ 20 μA	4.5 5.5	 1.2 1.4	 1.2 1.4	 1.2 1.4	 1.2 1.4	 1.2 1.4		
V _{T–} min	Minimum Positive–Going Input Threshold Voltage	V _O = 0.1 V or V _{CC} – 0.1 V I _{out} ≤ 20 μA	4.5 5.5	0.5 0.6	 0.5 0.6	 0.5 0.6	 0.5 0.6	 0.5 0.6		
V _H max	Maximum Hysteresis Voltage	V _O = 0.1 V or V _{CC} – 0.1 V I _{out} ≤ 20 μA	4.5 5.5	 1.4 1.5	 1.4 1.5	 1.4 1.5	 1.4 1.5	 1.4 1.5		
V _H min	Minimum Hysteresis Voltage	V _O = 0.1 V or V _{CC} – 0.1 V I _{out} ≤ 20 μA	4.5 5.5	0.4 0.4	 0.4 0.4	 0.4 0.4	 0.4 0.4	 0.4 0.4		
V _{OH}	Minimum High–Level Output Voltage	V _I < V _{T–} min I _{out} ≤ 20 μA	4.5 5.5	4.4 5.4	 4.4 5.4	 4.4 5.4	 4.4 5.4	 4.4 5.4	V	
		V _I < V _{T–} min I _{out} ≤ 4.0 mA	4.5	3.98	 3.84	 3.7	 3.7	 3.7		
V _{OL}	Maximum Low–Level Output Voltage	V _I ≥ V _{T+} max I _{out} ≤ 20 μA	4.5 5.5	 0.1 0.1	 0.1 0.1	 0.1 0.1	 0.1 0.1	 0.1 0.1	V	
		V _I ≥ V _{T+} max I _{out} ≤ 4.0 mA	4.5	 0.26	 0.33	 0.4	 0.4	 0.4		
I _{IK}	Maximum Input Leakage Current	V _I = V _{CC} or GND	5.5	 ± 0.1	 ± 1.0	 ± 1.0	 ± 1.0	 ± 1.0	μA	
I _{CC}	Maximum Quiescent Supply Current (per package)	V _I = V _{CC} or GND I _{out} = 0 μA	5.5	 1.0	 10	 40	 40	 40	μA	
ΔI _{CC}	Additional Quiescent Supply Current	V _I = 2.4 V, Any One Input V _I = V _{CC} or GND, Other Inputs I _{out} = 0 μA	5.5	≥ – 55°C		25°C to 125°C		mA		
				2.9		2.4				

9. Information on typical parametric values can be found in the ON Semiconductor High-Speed CMOS Data Book (DL129/D).

AC CHARACTERISTICS (C_L = 50 pF; Input t_r = t_f = 6.0 ns)

Symbol	Parameter	Test Conditions	Figures	Guaranteed Limit						Unit
				− 55°C to 25°C		≤ 85°C		≤ 125°C		
				Min	Max	Min	Max	Min	Max	
t _{PLH} , t _{PHL}	Maximum Propagation Delay, Input A to Output Y (L to H)	V _{CC} = 5.0 V ± 10% C _L = 50 pF, Input t _r = t _f = 6.0 ns	3 & 4		32		40		48	ns
t _{TLH} , t _{THL}	Maximum Output Transition Time, Any Output	V _{CC} = 5.0 V ± 10% C _L = 50 pF, Input t _r = t _f = 6.0 ns	3 & 4		15		19		22	ns

10. For propagation delays with loads other than 50 pF, and information on typical parametric values, see the ON Semiconductor High-Speed CMOS Data Book (DL129/D).

C _{PD}	Power Dissipation Capacitance, per Inverter (Note 11)	Typical @ 25°C, V _{CC} = 5.0 V	pF
		32	

11. Used to determine the no-load dynamic power consumption: P_D = C_{PD} V_{CC}²f + I_{CC} V_{CC}. For load considerations, see the ON Semiconductor High-Speed CMOS Data Book (DL129/D).

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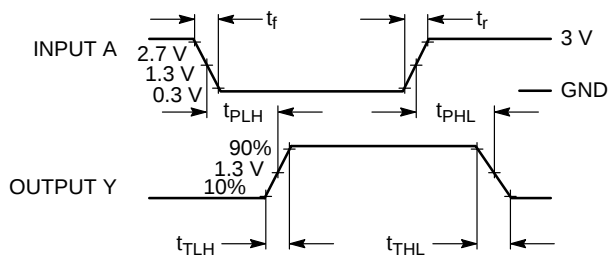
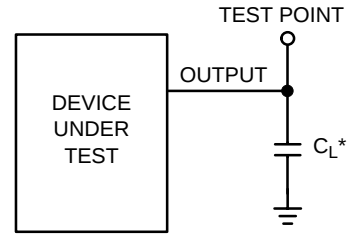


Figure 3. Switching Waveforms



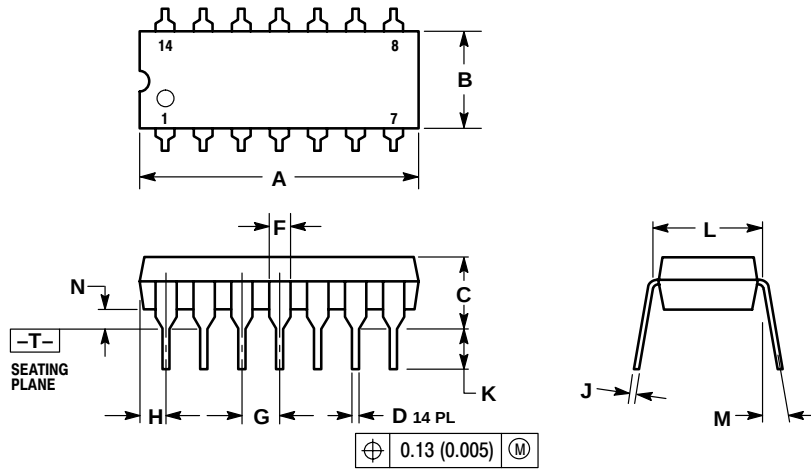
*Includes all probe and jig capacitance.

Figure 4. Test Circuit

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PACKAGE DIMENSIONS

PDIP-14
N SUFFIX
CASE 646-06
ISSUE M

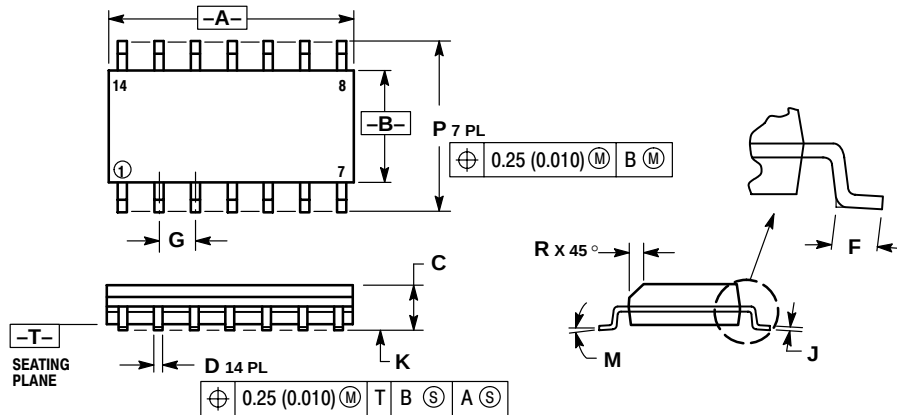


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.715	0.770	18.16	18.80
B	0.240	0.260	6.10	6.60
C	0.145	0.185	3.69	4.69
D	0.015	0.021	0.38	0.53
F	0.040	0.070	1.02	1.78
G	0.100 BSC		2.54 BSC	
H	0.052	0.095	1.32	2.41
J	0.008	0.015	0.20	0.38
K	0.115	0.135	2.92	3.43
L	0.290	0.310	7.37	7.87
M	---	10°	---	10°
N	0.015	0.039	0.38	1.01

SOIC-14
D SUFFIX
CASE 751A-03
ISSUE F



NOTES:

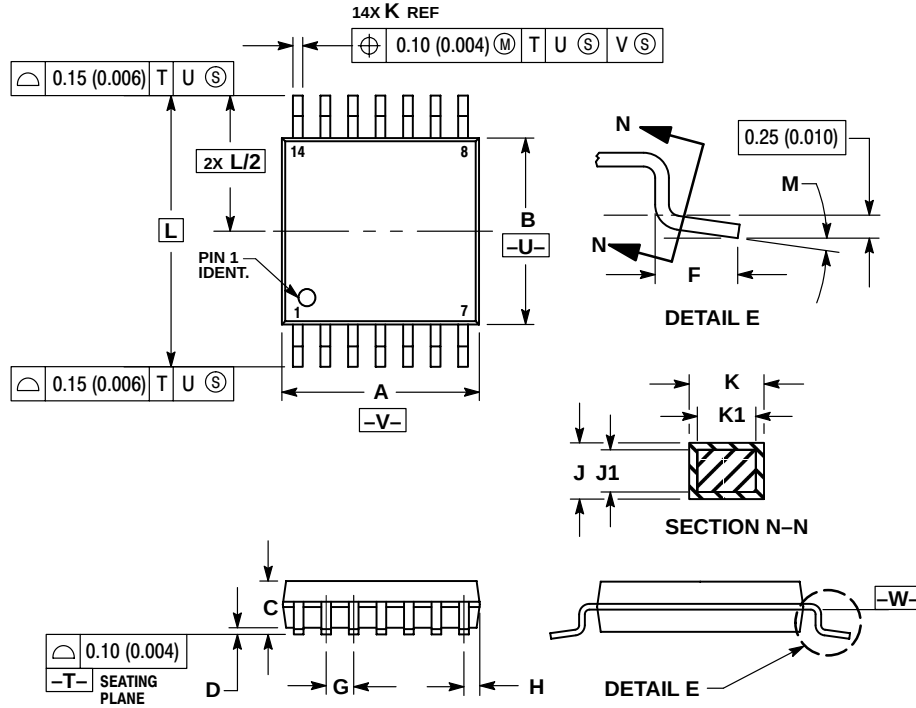
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	8.55	8.75	0.337	0.344
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.228	0.244
R	0.25	0.50	0.010	0.019

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PACKAGE DIMENSIONS

TSSOP-14
DT SUFFIX
CASE 948G-01
ISSUE O



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

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